



Bipolar PNP Bare Die – BTP6992

Part Description

The BTP6992 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -25V
- VCEO = -20V
- VEBO = -4V
- hFE = 150-800 @ VCE = -4V, IC = -0.1A
- VCE(Sat) = -0.5V @ IC = -0.5A, IB = -25mA
- fT = 180 MHz @ VCE = -6V, IE = 0A
- COBO = 12pF @ VCB = -10V

Features

Low VCE(sat). Designed to provide performance equivalent to 2SA1365

Die Size (Unawn)

650µm X 650µm, 26 Mils X 26 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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